

ST485ERB

±15 kV ESD protected, low power RS-485/RS-422 transceiver

Features

- Low quiescent current: 300 µA
- Designed for RS-485 interface application
- -7 V to 12 V common mode input voltage range
- Driver maintains high impedance in 3-state or with the power OFF
- 70 mV typical input hysteresis
- 30 ns propagation delay, 5 ns skew
- Operate from a single 5 V supply
- Current limiting and thermal shutdown for driver overload protection
- ESD protection:
 - ± 15 kV (HBM)
 - ± 8 kV (IEC-1000-4-2 contact discharge)
- Allows up to 256 transceivers on the bus

Description

The ST485ERB is al low power transceiver for RS-485 and RS-422 communication. Each driver output and receiver input is protected against \pm 15 kV electrostatic discharge (HBM) \pm 8 kV (IEC-1000-4-2 contact discharge) shocks, without latch-up. These parts contain one driver and one receiver.

This transceiver draws 300 μ A (typ.) of supply current when unloaded or fully loaded with disabled drivers.

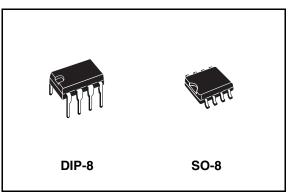
It operates from a single 5 V supply.

Driver is short-circuit current limited and is protected against excessive power dissipation by thermal shutdown circuitry that places the driver outputs into a high-impedance state.

Table 1.	Device summary
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Order code	Temperature range	Package	Packaging
ST485ERBN	- 40 to 85 °C	40 to 85 °C DIP-8 50 parts per tube / 40 tube pe	
ST485ERBDR	- 40 to 85 °C	SO-8 (tape and reel)	2500 parts per reel

February 2009



The ST485ERB is designed for bi-directional data communications on multipoint bus transmission line (half-duplex applications).

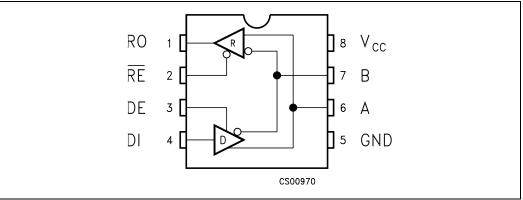
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1 Pin settings

Figure 1. Pin configuration



Pin n°	Symbol	Name and function
1	RO	Receiver output
2	RE	Receiver output enable
3	DE	Driver output enable
4	DI	Driver input
5	GND	Ground
6	A	Non-inverting receiver input and non-inverting driver output
7	В	Inverting receiver input and inverting driver output
8	V _{CC}	Supply voltage

2 Truth tables

Table 3.	Truth table	(driver)
Table J.	IT ULIT LADIE	unver

Inputs			Out	outs
RE DE DI			В	Α
Х	Н	Н	L	н
Х	Н	L	Н	L
Х	L	Х	Z	Z

Note: X = Don't care; Z = High impedance

Table 4. Truth table (recei

Inputs		Outputs	
RE	DE	A-B	RO
L	L	≥ +0.2V	н
L	L	≤ -0.2V	L
L	L	Inputs open	н
Н	L	Х	Z

Note: X = Don't care; Z = High impedance

3 Maximum ratings

	3 -		
Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	7	V
VI	Control input voltage (RE, DE)	-0.5 to (V _{CC} + 0.5)	V
V _{DI}	Driver input voltage (DI)	-0.5 to (V _{CC} + 0.5)	V
V _{DO}	Driver output voltage (A, B)	± 14	V
V _{RI}	Receiver input voltage (A, B)	± 14	V
V _{RO}	Receiver output voltage (RO)	-0.5 to (V _{CC} + 0.5)	V

Table 5. Absolute maximum ratings

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.



4 Electrical characteristics

Table 6. ESD performance: transmitter outputs, receiver inputs

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
ESD	ESD protection voltage	Human body model	±15			kV
ESD	ESD protection voltage	IEC-1000-4-2	±8			kV

 V_{CC} = 5 V ± 5 %, T_A = T_{MIN} to $T_{MAX},$ unless otherwise specified. Typical values are referred to T_A = 25 $^\circ C$

 Table 7.
 DC electrical characteristics

Symbol	Parameter	Test conditions ⁽¹⁾	Min.	Тур.	Max.	Unit
V _{OD1}	Differential driver output (no load)				5	V
V _{OD2}	Differential driver output (with load)	$R_L = 27\Omega$ (RS-485) (<i>Figure 2</i>) $R_L = 50\Omega$ (RS-422) (<i>Figure 2</i>)	1.5		5 5	V V
ΔV _{OD}	Change in magnitude of driver differential output voltage for complementary output states	R _L = 27Ω or 50Ω (<i>Figure 2</i>)			0.2	v
V _{OC}	Driver common-mode output voltage	R _L = 27Ω or 50Ω (<i>Figure 2</i>)			3	V
ΔV _{OC}	Change in magnitude of driver common-mode output voltage for complementary output states	R _L = 27Ω or 50Ω (<i>Figure 2</i>)			0.2	v
V _{IH}	Input high voltage	RE, DE, DI	2.0			V
V _{IL}	Input low voltage	RE, DE, DI			0.8	V
I _{IN1}	Input current	RE, DE, DI			±2	μA
I _{IN2}	Input current (A, B)	$\label{eq:VCM} \begin{array}{l} V_{CM} = 0V \text{ or } 5.25V, \ V_{DE} = 0V \\ V_{IN} = 12V \\ V_{IN} = -7V \end{array}$			1 -0.8	mA mA
V _{TH}	Receiver differential threshold voltage	V _{CM} = -7 to 12V	-0.2		0.2	V
ΔV_{TH}	Receiver input hysteresis	$V_{CM} = 0V$		70		mV
V _{OH}	Receiver output high voltage	I _O = -4mA, V _{ID} = 200mV	3.5			V
V _{OL}	Receiver output low voltage	I _O = 4mA, V _{ID} = -200mV			0.4	V
I _{OZR}	3-State (high impedance) output current at receiver	V _O = 0.4 to 2.4V			± 1	μA
R _{IN}	Receiver input resistance	V _{CM} = -7 to 12V	24			kΩ

Symbol	Parameter	Test conditions ⁽¹⁾	Min.	Тур.	Max.	Unit		
Icc	No load supply current ⁽²⁾	$V_{RE} = 0V \text{ or } V_{CC}$ $V_{DE} = V_{CC}$ $V_{DE} = 0V$		400 300	900 500	μΑ μΑ		
I _{OSD1}	Driver short-circuit current, V _O =High	$V_{O} = -7$ to 12V ⁽³⁾	35		250	mA		
I _{OSD2}	Driver short-circuit current, V _O =Low	$V_{O} = -7$ to 12V ⁽³⁾	35		250	mA		
I _{OSR}	Receiver short-circuit current	$V_{O} = 0V$ to V_{CC}	7		95	mA		

Table 7. DC electrical characteristics (continued)

1. All currents into device pins are positive; all cuttents out of device pins are negative; all voltages are referenced to device ground unless specified.

2. Supply current specification is valid for loaded transmitters when $V_{DE} = 0 V$

3. Applies to peak current. See typical Operating Characteristics.

(V_{CC} = 5 V \pm 5 %, T_A = T_{MIN} to T_MAX, unless otherwise specified. Typical values are referred to T_A = 25 °C)

Symbol	Parameter	Test conditions ⁽¹⁾	Min.	Тур.	Max.	Unit
t _{PLH} t _{PHL}	Propagation delay input to output	$R_{DIFF} = 54\Omega$, $C_{L1} = C_{L2} = 100pF$ (see <i>Figure 4</i> and <i>Figure 6</i>)	10	30	60	ns
t _{SK}	Output skew to output	$R_{DIFF} = 54\Omega$, $C_{L1} = C_{L2} = 100pF$ (see <i>Figure 4</i> and <i>Figure 6</i>)		5	10	ns
t _{TLH} t _{THL}	Rise or fall time	$R_{DIFF} = 54\Omega$, $C_{L1} = C_{L2} = 100pF$ (see <i>Figure 4</i> and <i>Figure 6</i>)	3	15	40	ns
t _{PZH}	Output enable time	C _L = 100pF, S2 = Closed (see <i>Figure 5</i> and <i>Figure 7</i>)		70	90	ns
t _{PZL}	Output enable time	C _L = 100pF, S1 = Closed (see <i>Figure 5</i> and <i>Figure 7</i>)		70	90	ns
t _{PLZ}	Output disable time	C _L = 15pF, S1 = Closed (see <i>Figure 5</i> and <i>Figure 7</i>)		70	90	ns
t _{PHZ}	Output disable time	C _L = 15pF, S2 = Closed (see <i>Figure 5</i> and <i>Figure 7</i>)		70	90	ns
C _{AB}	Output AB capacitance			43		pF

 Table 8.
 Driver switching characteristics

1. All currents into device pins are positive; all cuttents out of device pins are negative; all voltages are referenced to device ground unless specified.

(V_{CC} = 5 V \pm 5 %, T_A = T_{MIN} to T_MAX, unless otherwise specified. Typical values are referred to T_A = 25 °C)

Symbol	Parameter Test conditions ⁽¹⁾		Min.	Тур.	Max.	Unit
t _{PLH} t _{PHL}	Propagation delay input to output	$R_{DIFF} = 54\Omega, C_{L1} = C_{L2} = 100 pF$ (see <i>Figure 4</i> and <i>Figure 8</i>)	20	130	210	ns
t _{SKD}	Differential receiver skew	$R_{\text{DIFF}} = 54\Omega, C_{\text{L1}} = C_{\text{L2}} = 100\text{pF}$ (see <i>Figure 4</i> and <i>Figure 8</i>) 13			ns	
t _{PZH}	Output enable time	C _{RL} = 15pF, S1 = Closed (see <i>Figure 2</i> and <i>Figure 9</i>)		20	50	ns
t _{PZL}	Output enable time	C _{RL} = 15pF, S2 = Closed (see <i>Figure 2</i> and <i>Figure 9</i>)		20	50	ns
t _{PLZ}	Output disable time	C _{RL} = 15pF, S1 = Closed (see <i>Figure 2</i> and <i>Figure 9</i>)		20	50	ns
t _{PHZ}	Output disable time	C _{RL} = 15pF, S2 = Closed (see <i>Figure 2</i> and <i>Figure 9</i>)		20	50	ns
f _{MAX}	Maximum data rate		2.5			Mbps

 Table 9.
 Receiver switching characteristics

1. All currents into device pins are positive; all cuttents out of device pins are negative; all voltages are referenced to device ground unless specified

5 Test circuit and typical characteristics

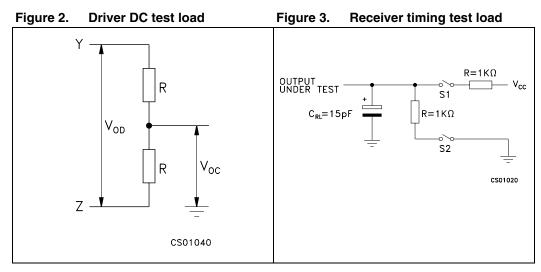
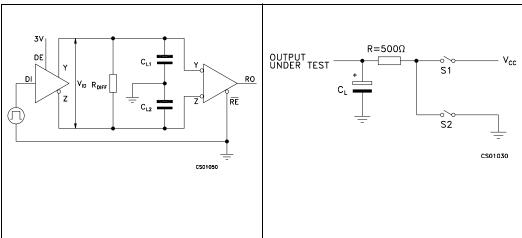


Figure 4. Drive/receiver timing test Figure 5. Driver timing test load circuit



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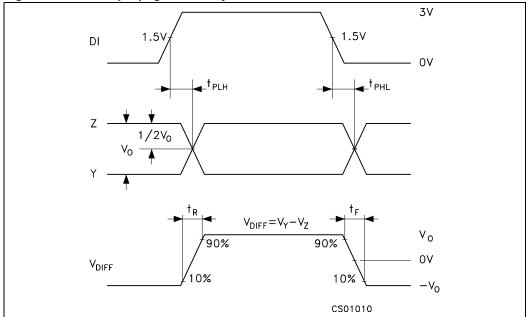
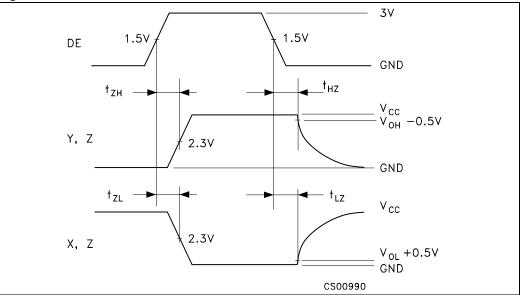
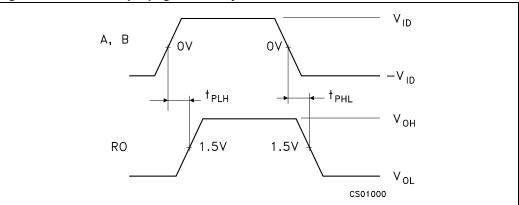


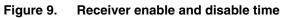
Figure 6. Driver propagation delay

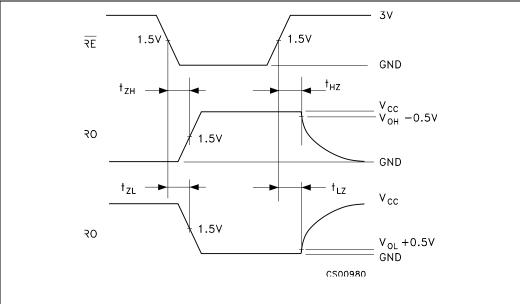












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Figure 10. Receiver output current vs. output Figure 11. Receiver output current vs. output low voltage

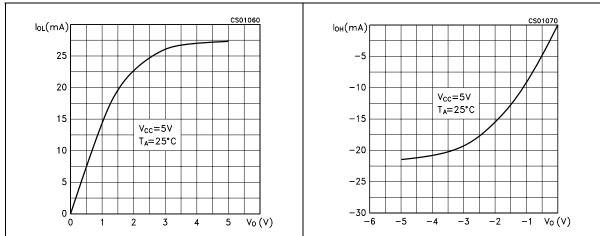
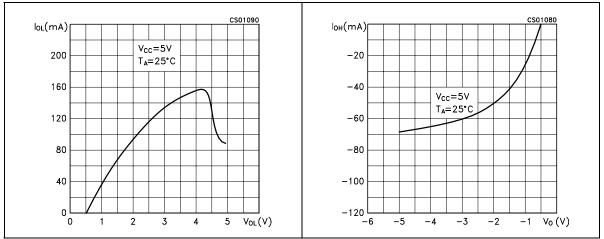
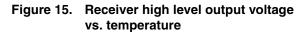
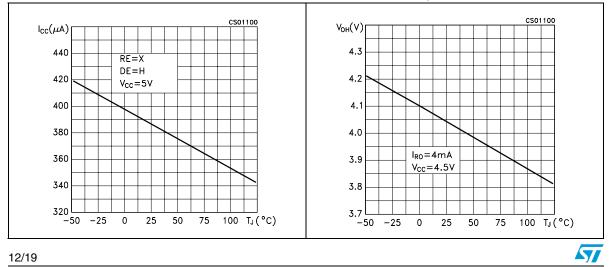


Figure 12. Driver output current vs. output low Figure 13. Driver output current vs. output voltage









CS01120 CS01130 $V_{OL}(V)$ $V_{OD}(V)$ 0.40 4.5 NO LOAD 0.35 4.0 0.30 3.5 V_{cc}=4.5V 0.25 3.0 $R_L = 50\Omega$ I_{RO}=4mA V_{CC}=4.5V 0.20 2.5 $R_L = 27\Omega$ 0.15 2.0 0.10 -50 1.5 -50 -25 100 T」(°C) 50 100 T_J(°C) -25 25 75 75 0 50 0 25

Figure 16. Receiver low level output voltage vs. temperature

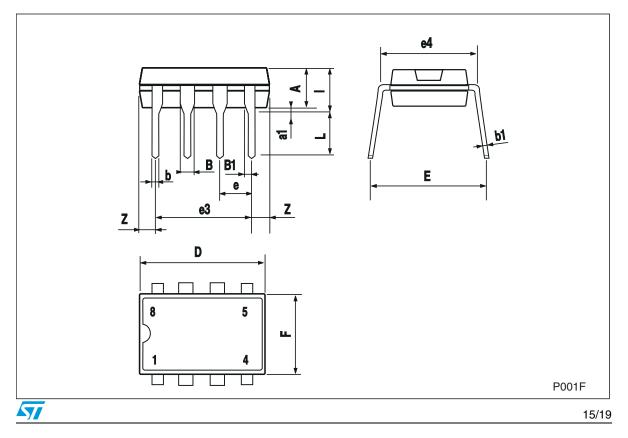
Figure 17. Differential driver output voltage vs. temperature

6 Package mechanical data

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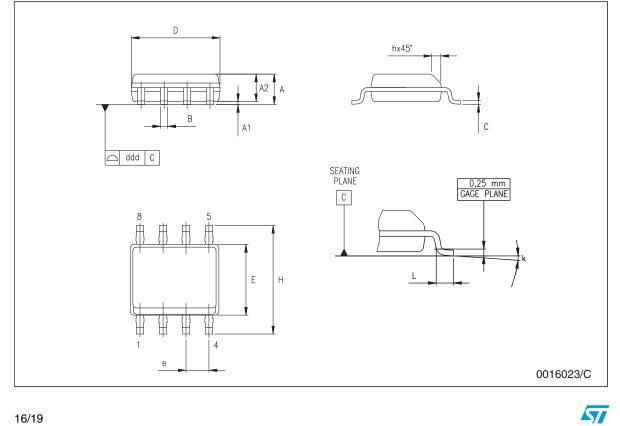
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	Plastic DIP-8 mechanical data						
Dim.		mm.					
Din.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А		3.3			0.130		
a1	0.7			0.028			
В	1.39		1.65	0.055		0.065	
B1	0.91		1.04	0.036		0.041	
b		0.5			0.020		
b1	0.38		0.5	0.015		0.020	
D			9.8			0.386	
Е		8.8			0.346		
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			7.1			0.280	
I			4.8			0.189	
L		3.3			0.130		
Z	0.44		1.6	0.017		0.063	



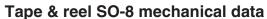
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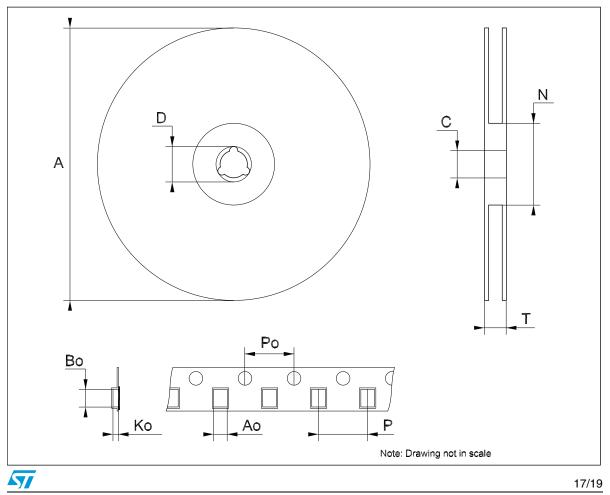
	SO-8 mechanical data						
Dim.		mm.			inch.		
Dini.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	1.35		1.75	0.053		0.069	
A1	0.10		0.25	0.04		0.010	
A2	1.10		1.65	0.043		0.065	
В	0.33		0.51	0.013		0.020	
С	0.19		0.25	0.007		0.010	
D	4.80		5.00	0.189		0.197	
E	3.80		4.00	0.150		0.157	
е		1.27			0.050		
Н	5.80		6.20	0.228		0.244	
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
k	8° (max.)						
ddd			0.1			0.04	



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Dia	mm.			inch.			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
Ν	60			2.362			
Т			22.4			0.882	
Ao	8.1		8.5	0.319		0.335	
Bo	5.5		5.9	0.216		0.232	
Ko	2.1		2.3	0.082		0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	





7 Revision history

Date	Revision	Changes
21-Mar-2006	3	Order codes has been updated and new template.
01-Aug-2006	4	Mistake in cover page description 300 mA ==> 300 μ A.
25-Oct-2006	5	Order codes updated.
02-Dec-2008	6	Modified: device name Table 1 on page 1.
16-Feb-2008	7	Modified <i>Note: on page 5</i> .

Table 10.Document revision history



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